



Science & Technology Facilities Council

**Technology**

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**Investigation of the position resolution  
of the HOTWAXS Detector  
(Imaging at Higher X-ray Energies (10keV –30keV))**

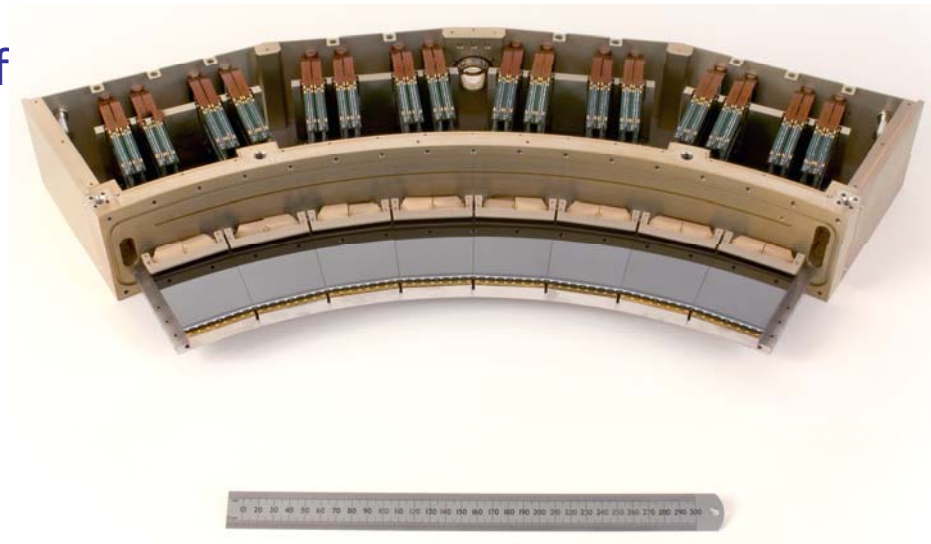
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## What is HOTWAXS?

- 512 independent channels of preamplifier, scaler and discriminator
- Channel count rate of 1 MHz, Global count rate 500 MHz
- 60° angular coverage, 400mm sample to detector distance
- 50mm active gas depth

**see NIM A580 (2007) p1526**



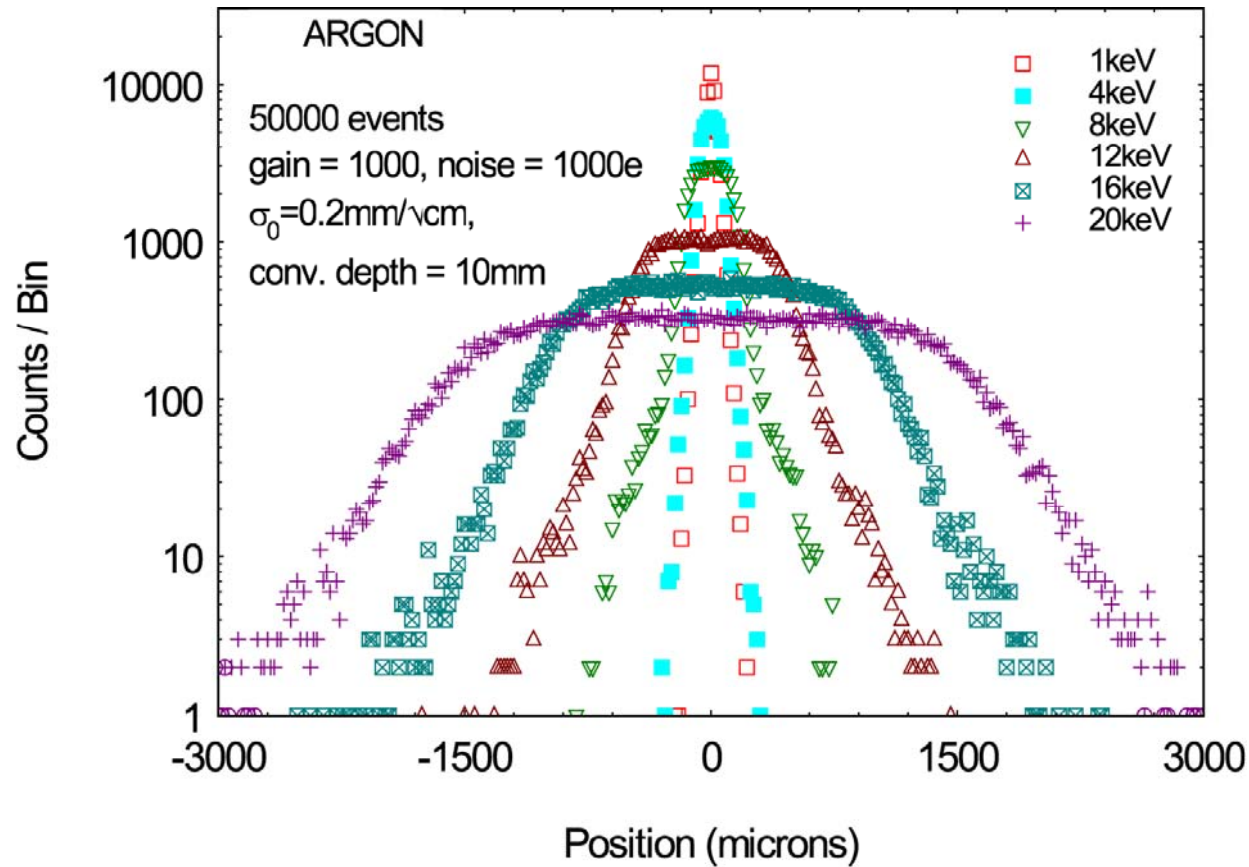


## Imaging above 10keV

- For  $E_x < 10\text{keV}$  resolution governed by convolution of electronic noise, secondary electron diffusion and primary photoelectron range - leads to quasi-normal charge footprint
- For  $E_x > 10\text{keV}$  resolution photoelectron range dominates, varies as  $E_{pe}^{1.7}$  So resolution rapid function of  $E_x$
- HOTWAXS pixellated readout with LLD as only parameter, limits low energy resolution, but less severe increase in FWHM as  $E_x$  increases (at sacrifice of efficiency)



## Charge footprint from simulation





In argon, K shell vacancy left with stored energy of 3.2keV which is dissipated locally in auger electrons (with max range of  $\sim 200\mu\text{m}$ )

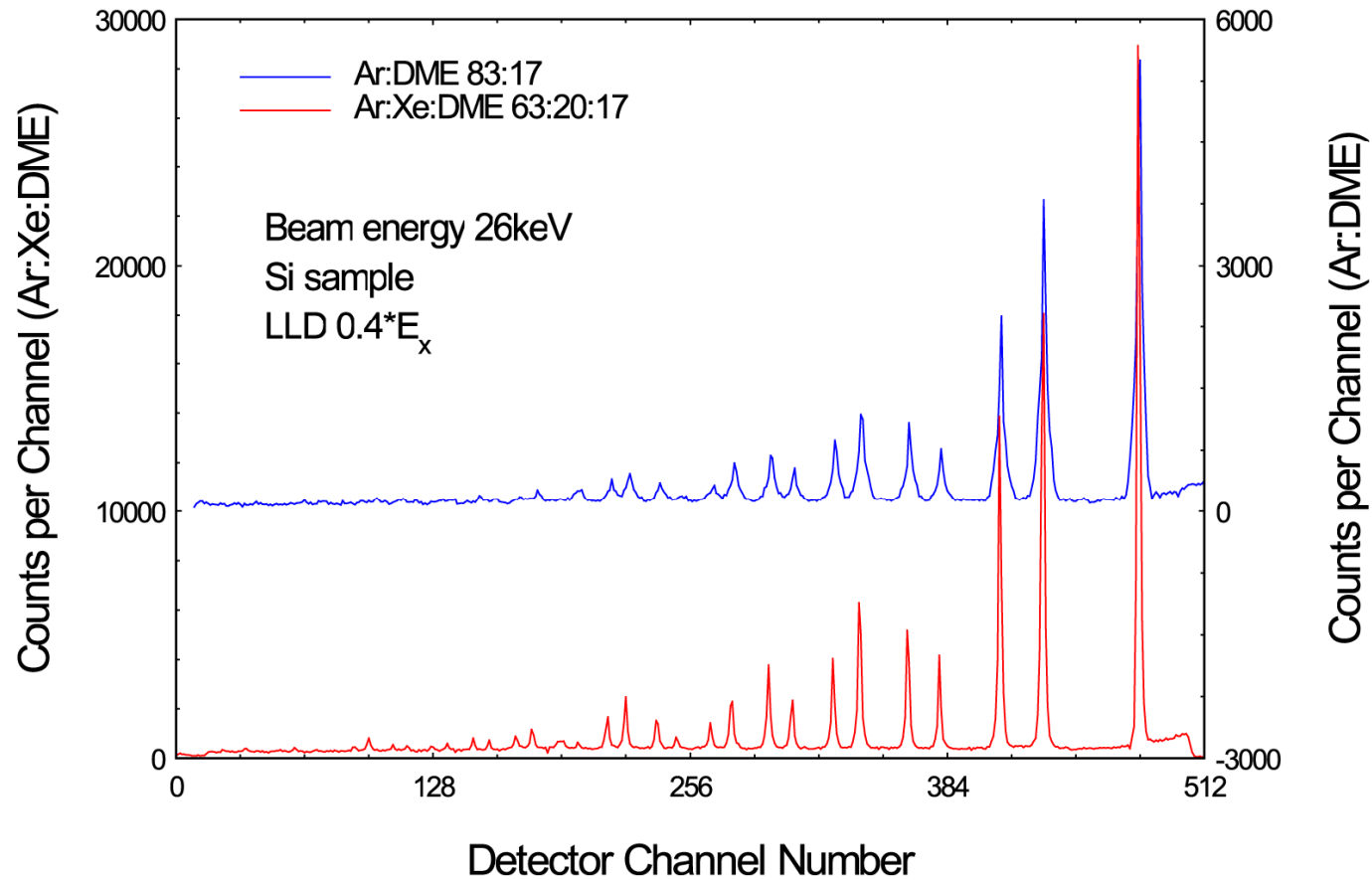
In xenon, L shell vacancy, energy of 5.1keV, dissipated in  $\sim 100\mu\text{m}$

Since these dimensions are small compared to HOTWAXS strip width, there is a punctual deposit at the X-ray interaction point of  $\sim 119$  electrons for Ar, and  $\sim 189$  electrons for Xe

As  $E_x$  increases, linear deposit of long range photoelectron energy in any strip decreases (as  $E_x/E_x^{1.7}$ ) So that with a high LLD, the extra deposit in the ‘correct’ strip can be preferentially detected

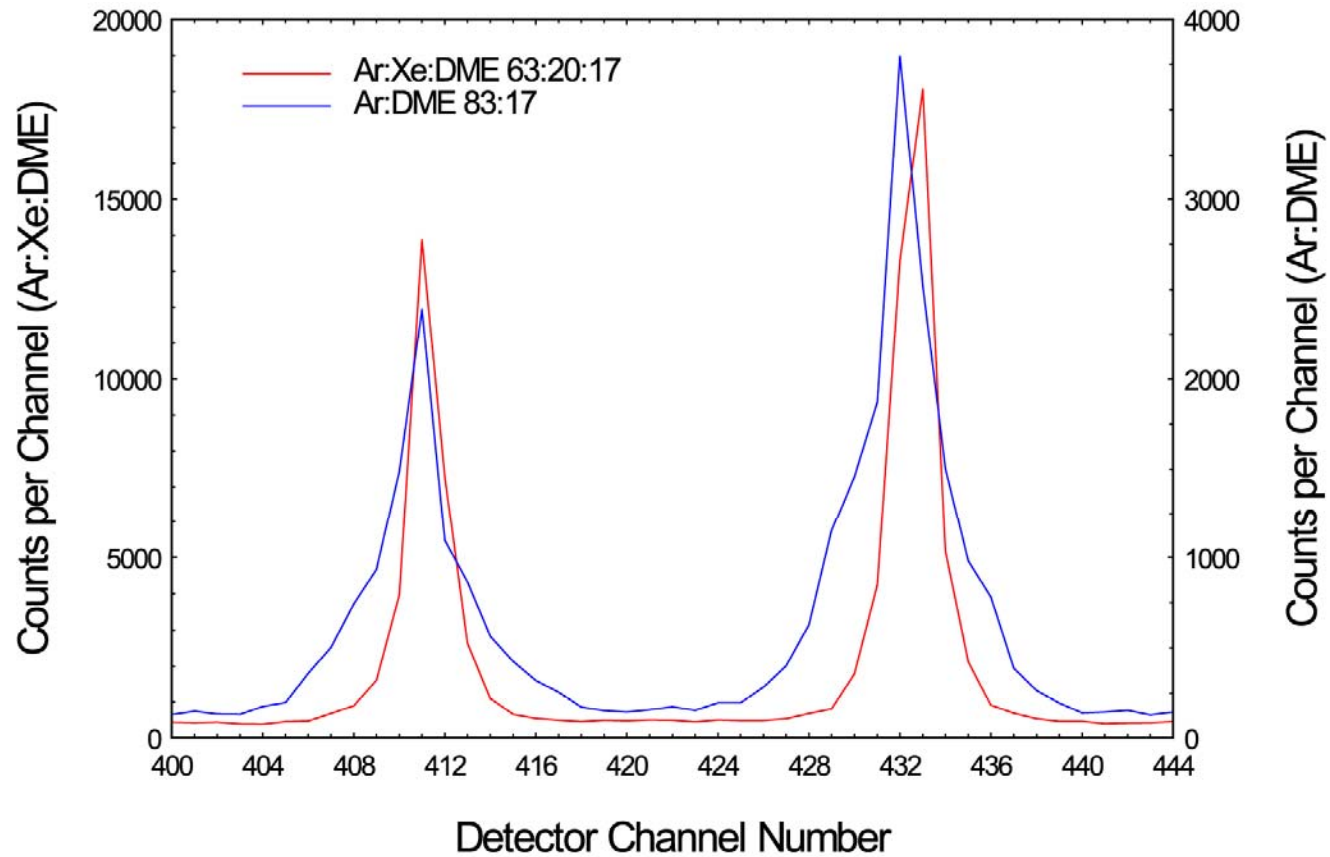


## Si diffraction at 26keV



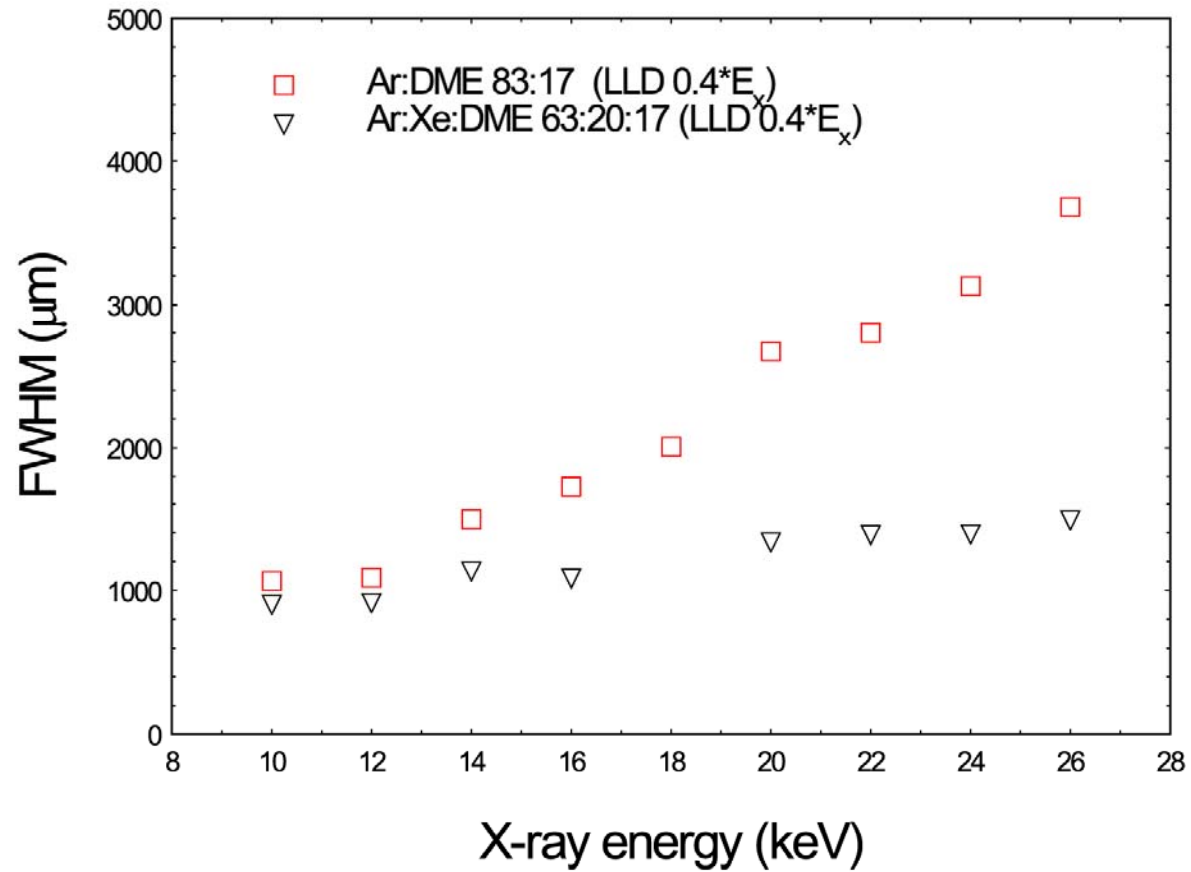


## Si diffraction at 26keV





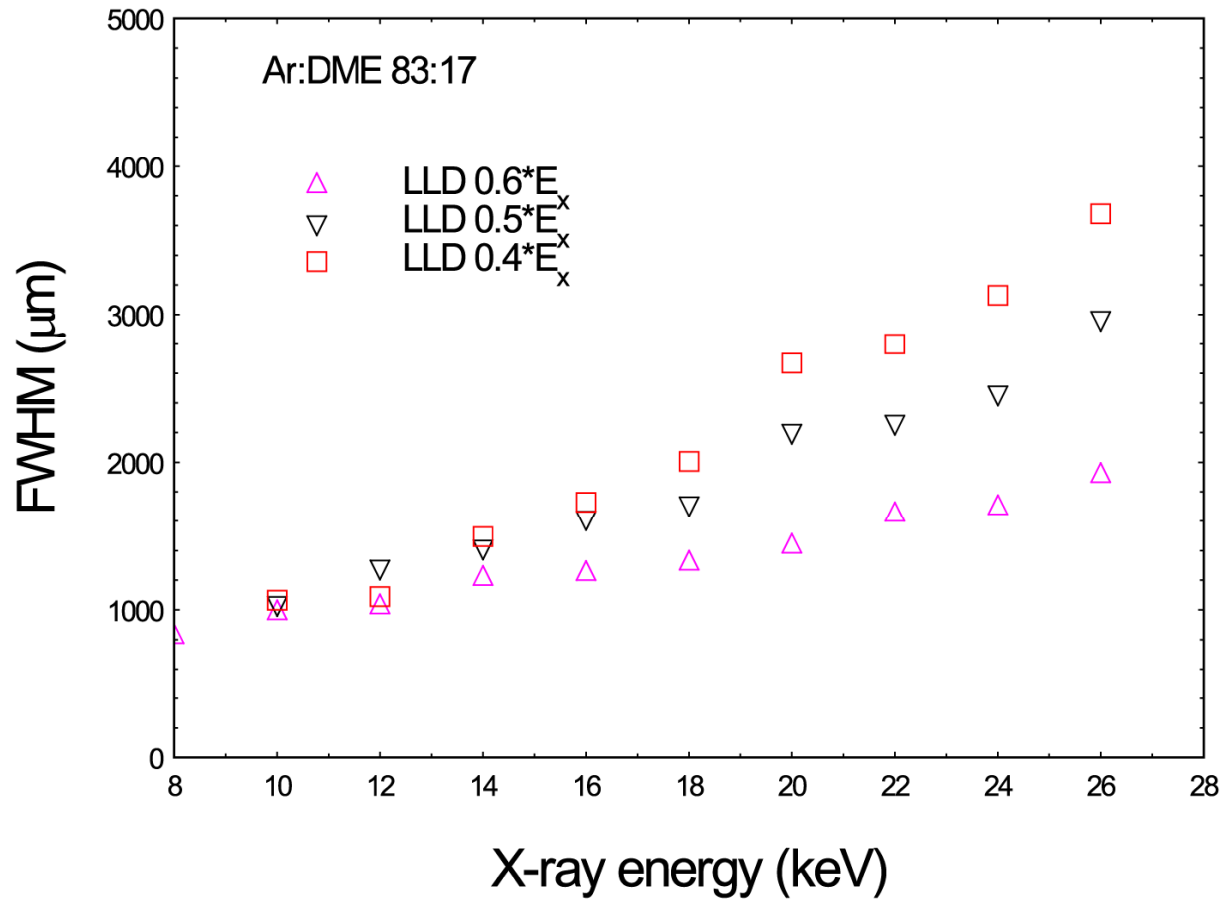
## FWHM resolution variation with X-ray energy





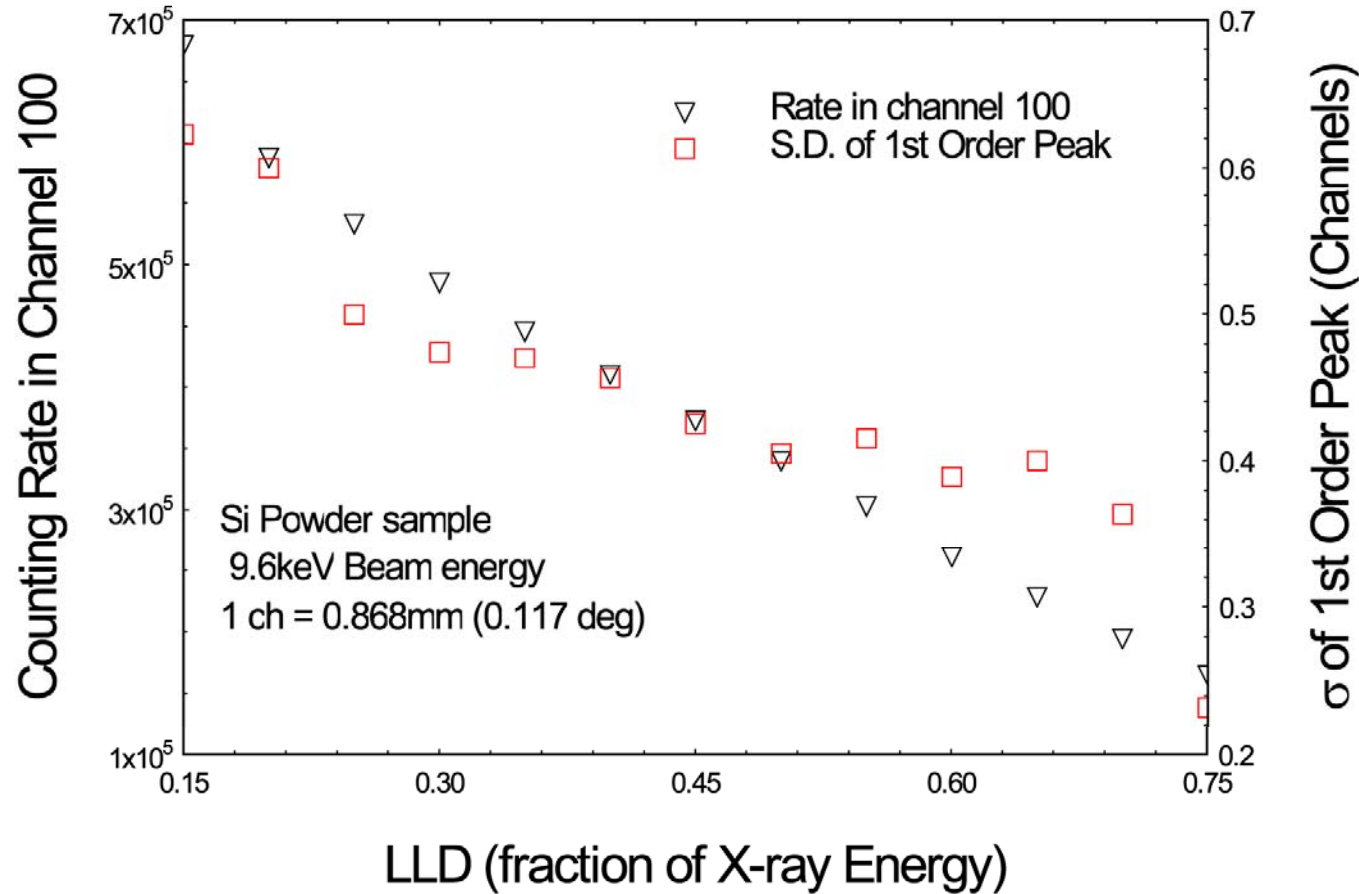


## FHWM resolution variation with LLD



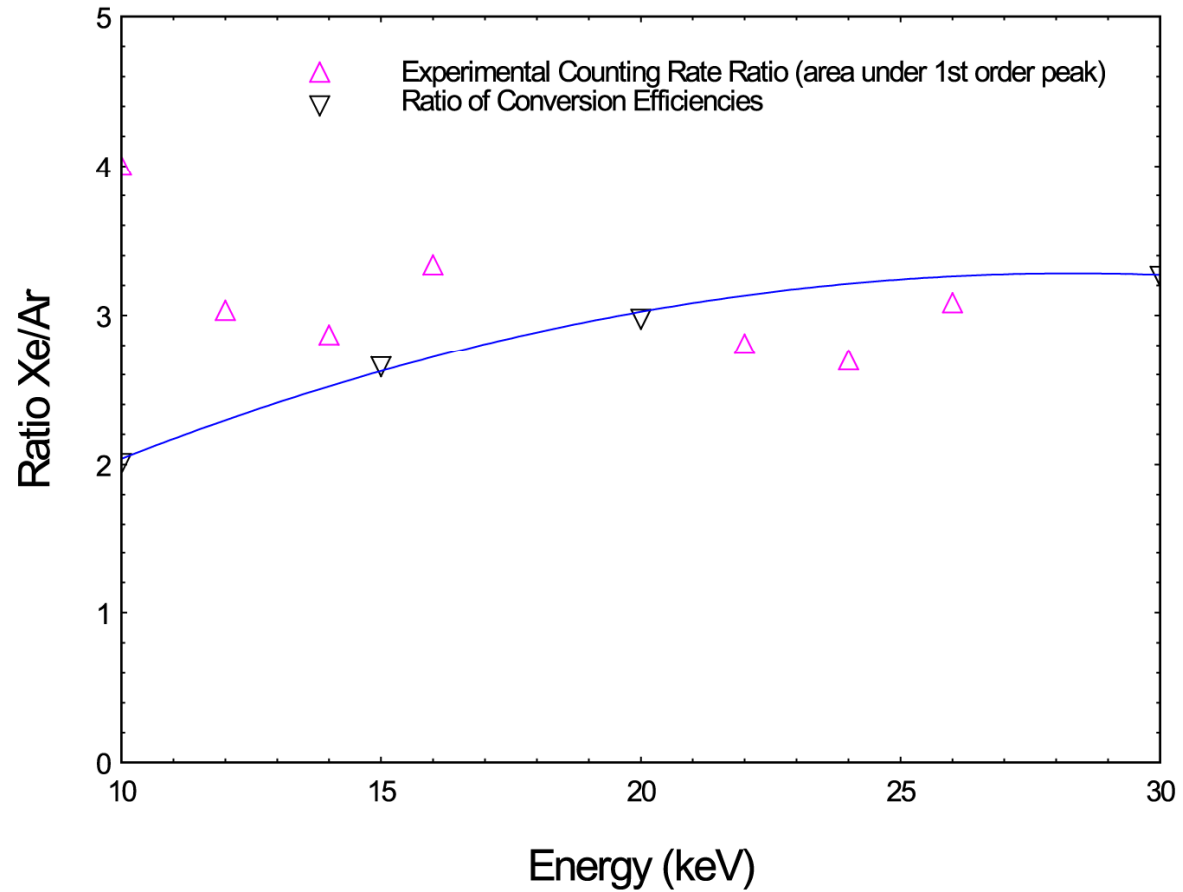


## Resolution and count variation with LLD



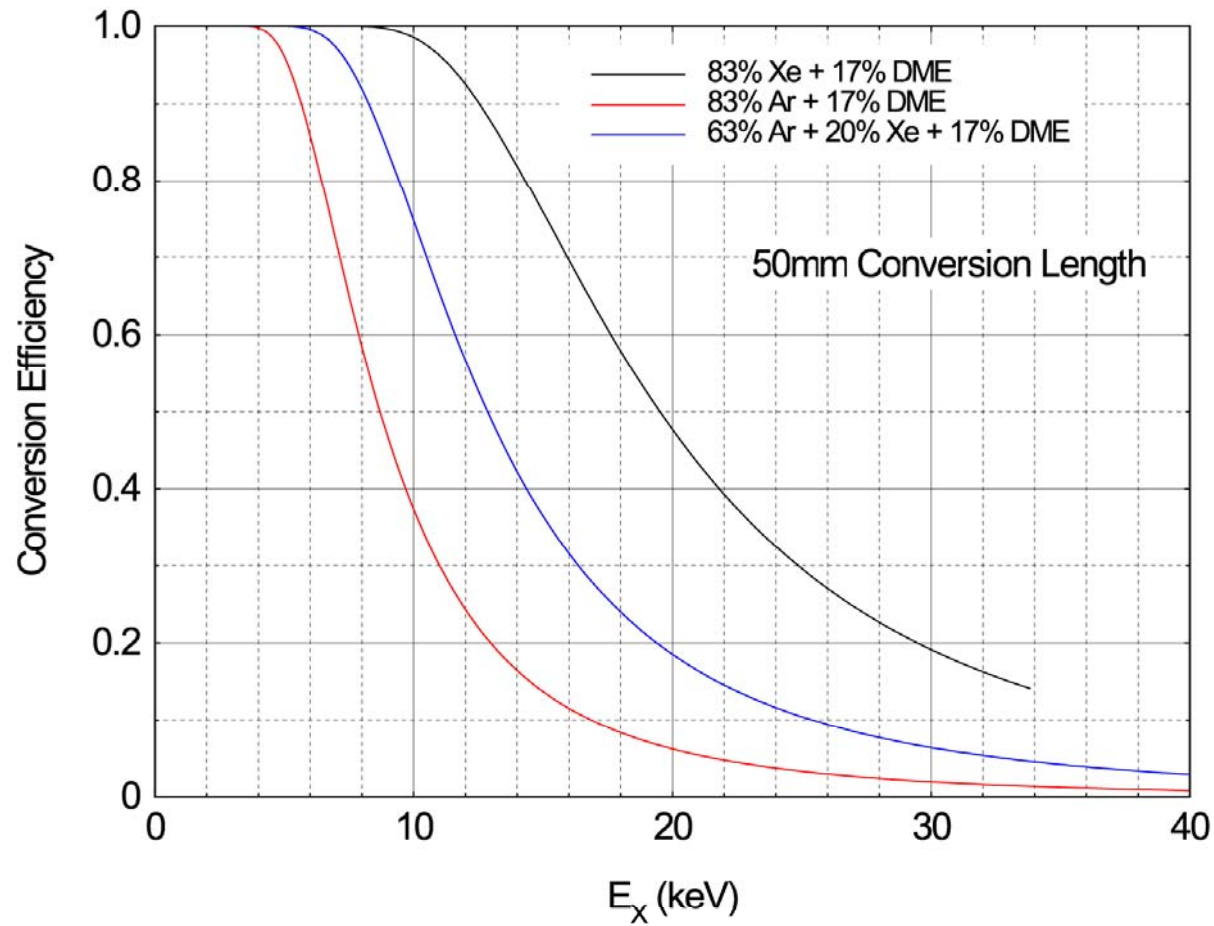


## Experimental count ratio of 2 gas mixtures



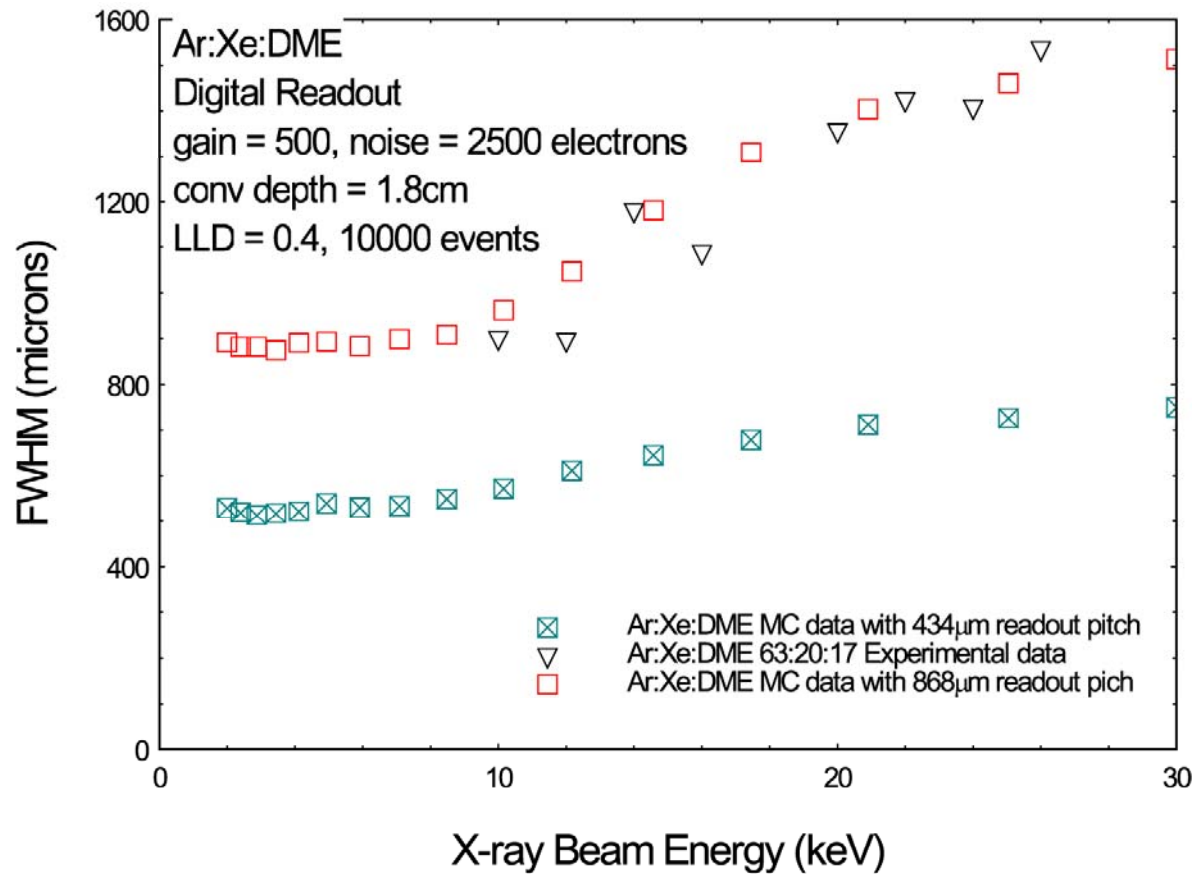


## Theoretical conversion efficiencies



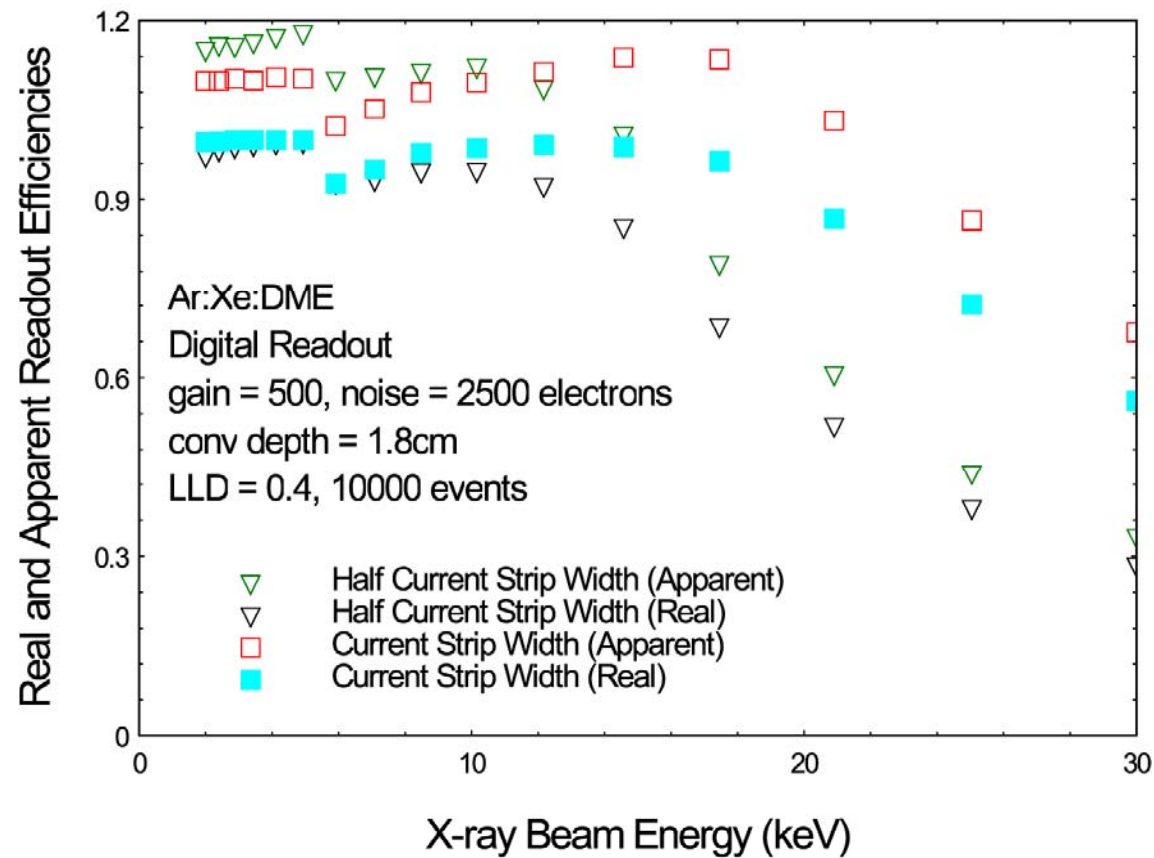


## Effect of reduced pitch (simulation)





## Efficiency comparison of two pitch geometries (simulation)





## Conclusions and future work

Addition of 20% or more xenon to gas improves resolution drastically (and conversion efficiency)

Complete substitution of Ar for Xe offers much improved performance if able to recycle Xe

Instrumenting each channel offers possibility of sub mm resolution at 30keV (ASIC readout chip - FREDAs)